

POWER SCHOTTKY RECTIFIER

Table 1: Main Product Characteristics

$I_{F(AV)}$	10 A
V_{RRM}	45 V
T_j	175°C
$V_F(\text{max})$	0.57 V

FEATURES AND BENEFITS

- Negligible switching losses
- Low forward drop
- Low capacitance
- High reverse avalanche surge capability
- Avalanche specification

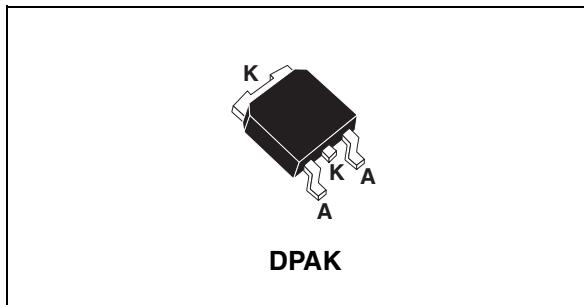


Table 2: Order Codes

Part Number	Marking
STPS1045B	S1045
STPS1045B-TR	S1045

DESCRIPTION

High voltage Schottky rectifier suited for Switch Mode Power Supplies and other Power Converters.

Packaged in DPAK, this device is intended for use in high frequency circuitries where low switching losses are required.

Table 3: Absolute Maximum Ratings

Symbol	Parameter		Value	Unit
V_{RRM}	Repetitive peak reverse voltage		45	V
$I_{F(\text{RMS})} / \text{pin}$	RMS forward voltage		7	A
$I_{F(AV)}$	Average forward current	$T_c = 150^\circ\text{C}$ $\delta = 0.5$	10	A
I_{FSM}	Surge non repetitive forward current	$t_p = 10\text{ms}$ sinusoidal	75	A
I_{RRM}	Repetitive peak reverse current	$t_p = 2\mu\text{s}$ $F = 1\text{KHz}$	1	A
P_{ARM}	Repetitive peak avalanche power	$t_p = 1\mu\text{s}$ $T_j = 25^\circ\text{C}$	4000	W
T_{stg}	Storage temperature range		-65 to + 175	°C
T_j	Maximum operating junction temperature		175	°C
dV/dt	Critical rate of rise of reverse voltage		10000	V/ μs

STPS1045B

Table 4: Thermal Parameters

Symbol	Parameter	Value	Unit
R _{th(j-c)}	Junction to case	3	°C/W

Table 5: Static Electrical Characteristics

Symbol	Parameter	Tests conditions	Min.	Typ	Max.	Unit	
I _R *	Reverse leakage current	T _j = 25°C	V _R = V _{RRM}			100	µA
		T _j = 125°C		7	15		mA
V _F **	Forward voltage drop	T _j = 25°C	I _F = 10A		0.63	V	
		T _j = 125°C		0.50	0.57		
		T _j = 25°C	I _F = 20A		0.84		
		T _j = 125°C		0.65	0.72		

Pulse test: * tp = 5 ms, δ < 2%

** tp = 380 µs, δ < 2%

To evaluate the conduction losses use the following equation: P = 0.42 × I_{F(AV)} + 0.015 I_F² (RMS)

Figure 1: Average forward power dissipation versus average forward current

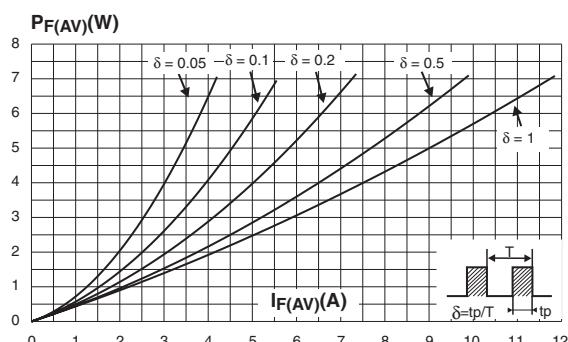


Figure 2: Average forward current versus ambient temperature (δ = 0.5)

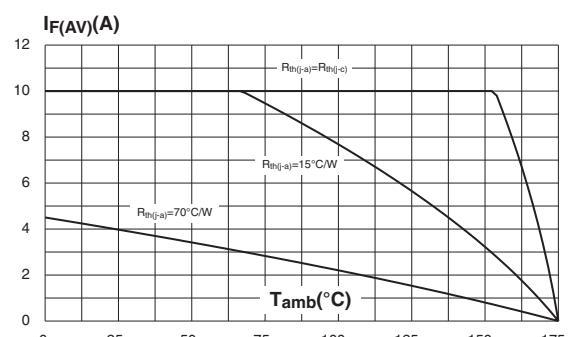


Figure 3: Normalized avalanche power derating versus pulse duration

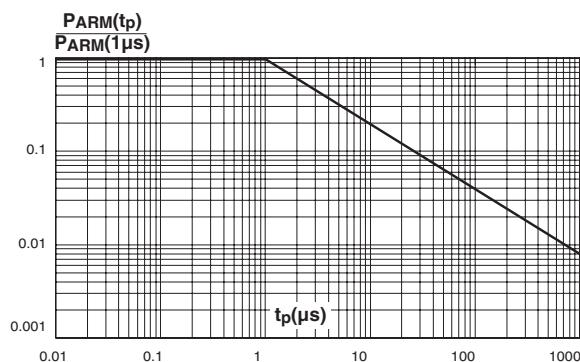


Figure 4: Normalized avalanche power derating versus junction temperature

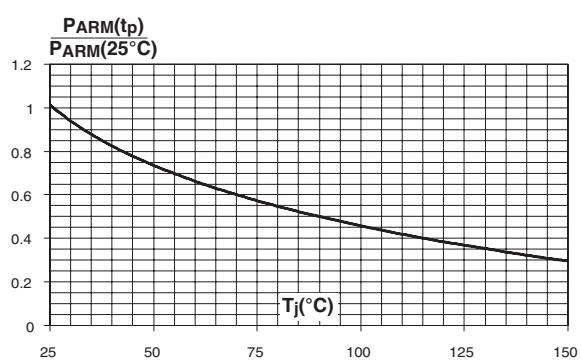


Figure 5: Non repetitive surge peak forward current versus overload duration (maximum values)

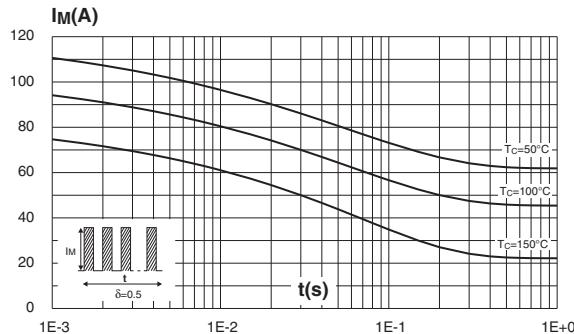


Figure 7: Reverse leakage current versus reverse voltage applied (typical values)

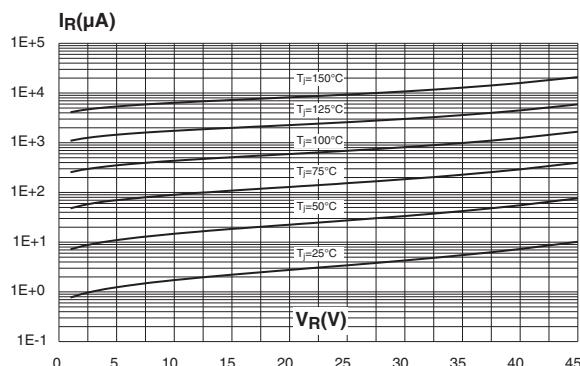


Figure 9: Forward voltage drop versus forward current

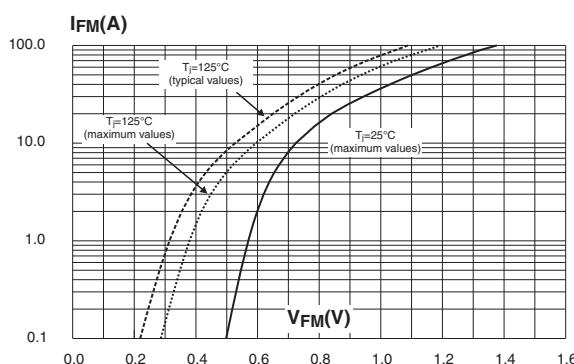


Figure 6: Relative variation of thermal impedance junction to case versus pulse duration

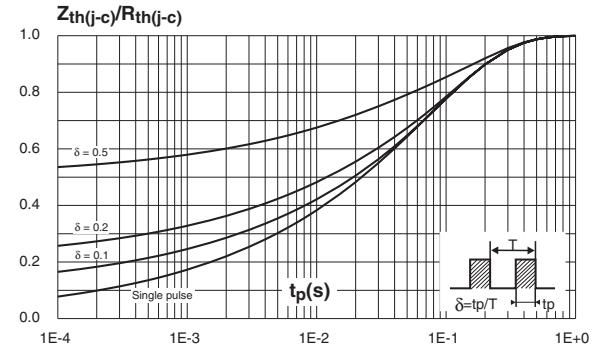


Figure 8: Junction capacitance versus reverse voltage applied (typical values)

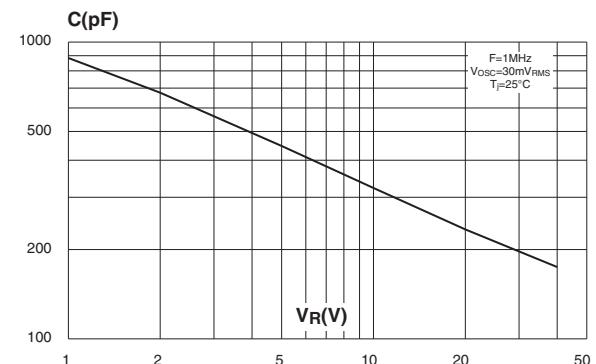
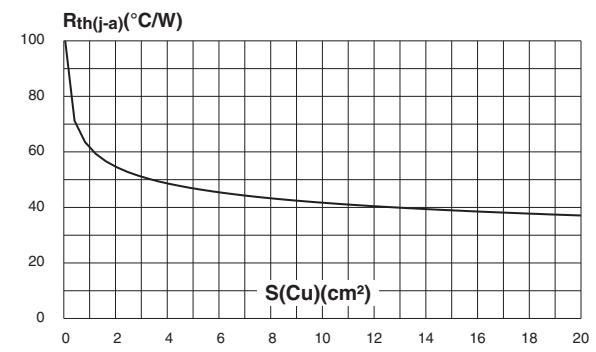


Figure 10: Thermal resistance junction to ambient versus copper surface under tab (Epoxy printed circuit board, copper thickness: 35μm)



STPS1045B

Figure 11: DPAK Package Mechanical Data

REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max	Min.	Max.
A	2.20	2.40	0.086	0.094
A1	0.90	1.10	0.035	0.043
A2	0.03	0.23	0.001	0.009
B	0.64	0.90	0.025	0.035
B2	5.20	5.40	0.204	0.212
C	0.45	0.60	0.017	0.023
C2	0.48	0.60	0.018	0.023
D	6.00	6.20	0.236	0.244
E	6.40	6.60	0.251	0.259
G	4.40	4.60	0.173	0.181
H	9.35	10.10	0.368	0.397
L2	0.80 typ.		0.031 typ.	
L4	0.60	1.00	0.023	0.039
V2	0°	8°	0°	8°

Figure 12: Foot Print Dimensions (in millimeters)

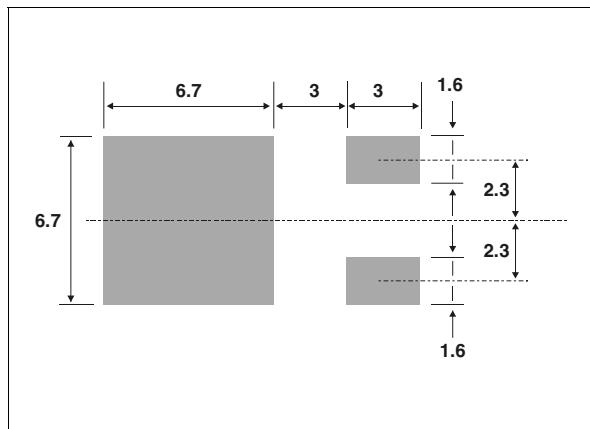


Table 6: Ordering Information

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STPS1045B	S1045	DPAK	0.30 g	75	Tube
STPS1045B-TR	S1045			2500	Tape & reel

- Cooling method: by conduction (C)

Table 7: Revision History

Date	Revision	Description of Changes
Jul-2003	3B	Last issue.
21-Apr-2005	4	IPAK package removed.
03-Nov-2005	5	DPAK Foot Print dimensions updated.

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